

Dual Switching Diodes

FEATURE

- Small plastic SMD package.
- For high-speed switching applications.
- We declare that the material of product compliance with RoHS requirements.
- S- Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

DEVICE MARKING AND ORDERING INFORMATION

Device	Marking	Shipping
LBAV70WT1G S-LBAV70WT1G	A4	3000/Tape&Reel
LBAV70WT3G S-LBAV70WT3G	A4	10000/Tape&Reel

MAXIMUM RATINGS (T_A = 25°C)

Rating	Symbol	Max	Unit
Reverse Voltage	V _R	70	Vdc
Forward Current	I _F	200	mAdc
Peak Forward Surge Current	I _{FM(surge)}	500	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board ⁽¹⁾ T _A = 25°C	P _D	200	mW
Derate above 25°C		1.6	mW/°C
Thermal Resistance, Junction to Ambient	R _{θJA}	625	°C/W
Total Device Dissipation Alumina Substrate ⁽²⁾ T _A = 25°C	P _D	300	mW
Derate above 25°C		2.4	mW/°C
Thermal Resistance, Junction to Ambient	R _{θJA}	417	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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OFF CHARACTERISTICS

Reverse Breakdown Voltage (I _{BR} = 100 μAdc)	V _{BR}	70	—	Vdc
Reverse Voltage Leakage Current (V _R = 70 Vdc)	I _{R1}	—	5.0	μAdc
(V _R = 50 Vdc)	I _{R2}	—	100	nAdc
Diode Capacitance (V _R = 0, f = 1.0 MHz)	C _D	—	1.5	pF
Forward Voltage (I _F = 1.0 mAdc)	V _F	—	715	mVdc
(I _F = 10 mAdc)		—	855	
(I _F = 50 mAdc)		—	1000	
(I _F = 150 mAdc)		—	1250	
Reverse Recovery Time (I _F = I _R = 10 mAdc, R _L = 100Ω, I _{R(REC)} = 1.0 mAdc) (Figure 1)	t _{rr}	—	6.0	ns
Forward Recovery Voltage (I _F = 10 mAdc, t _r = 20 ns) (Figure 2)	V _{RF}	—	1.75	V

1. FR-5 = 1.0 × 0.75 × 0.062 in.

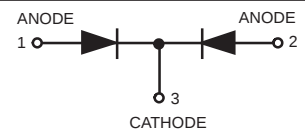
2. Alumina = 0.4 × 0.3 × 0.024 in. 99.5% alumina.

3. For each individual diode while the second diode is unbiased.

LBAV70WT1G
S-LBAV70WT1G



SC-70



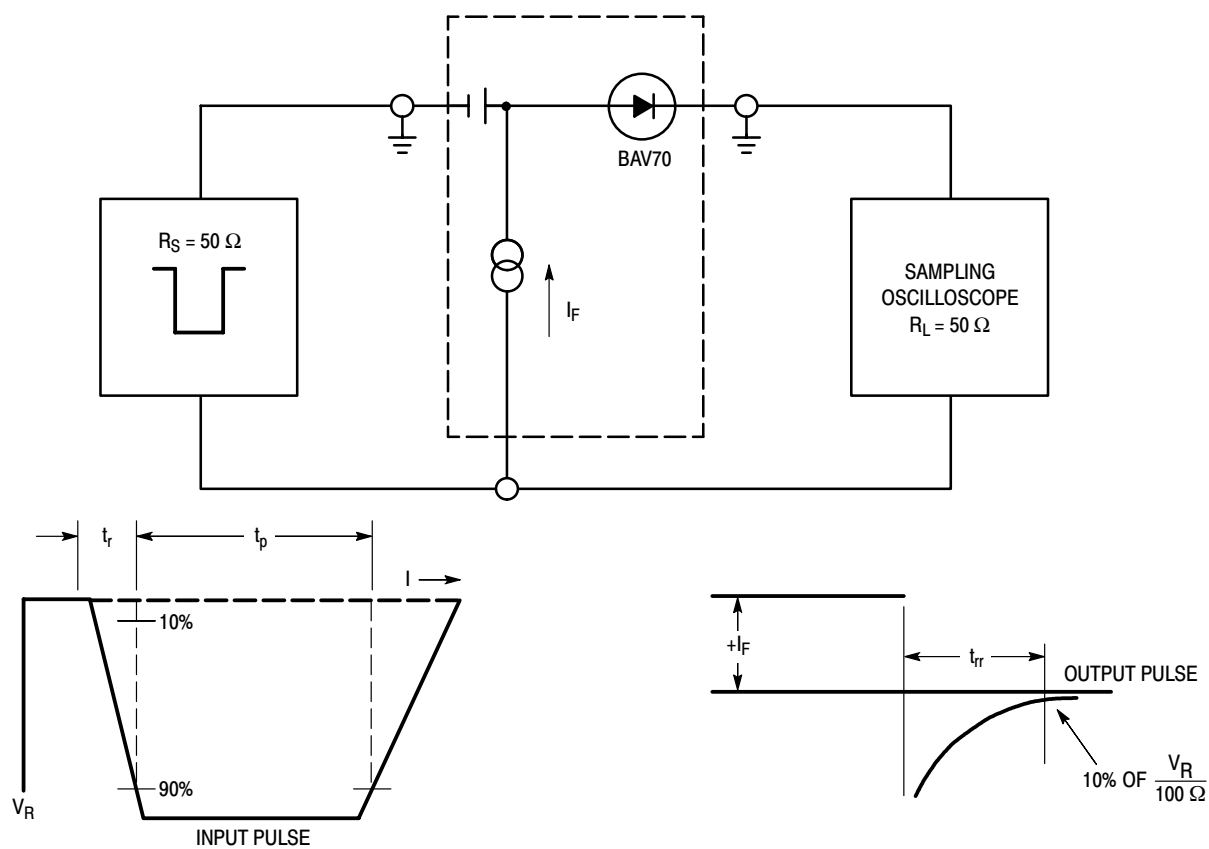


Figure 1. Recovery Time Equivalent Test Circuit

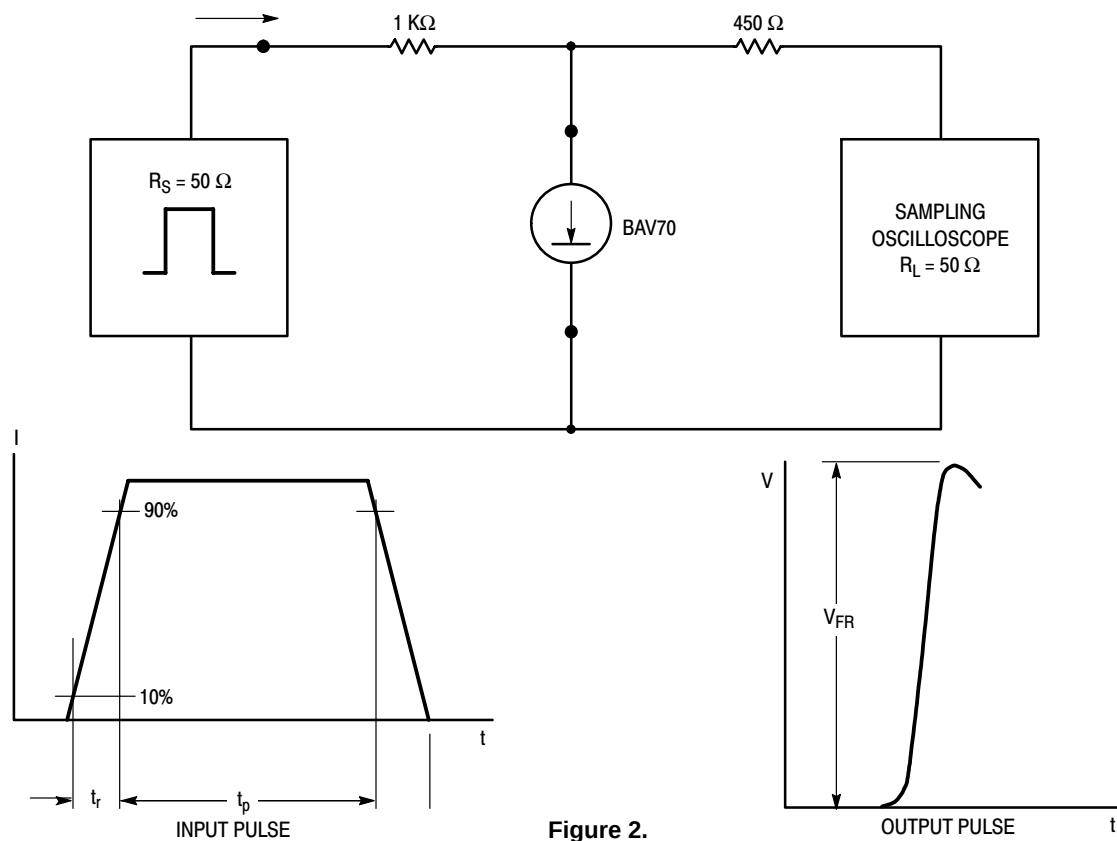
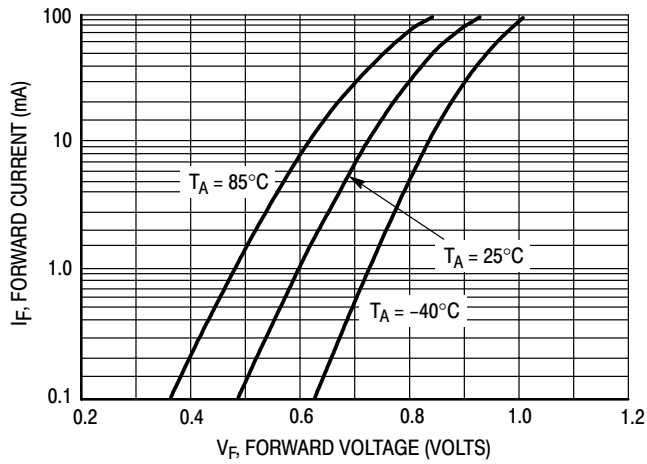
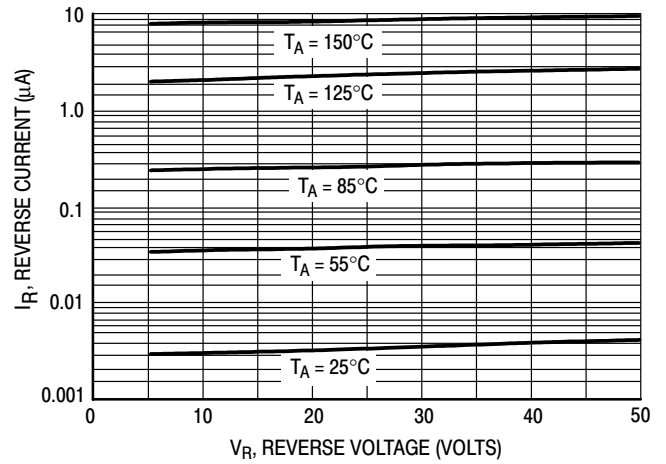
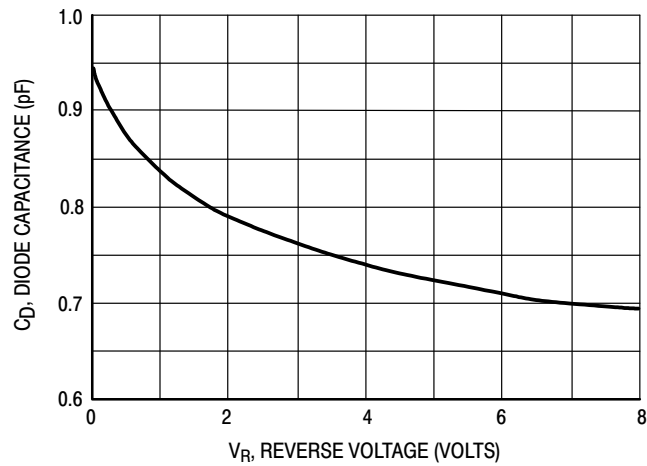


Figure 2.

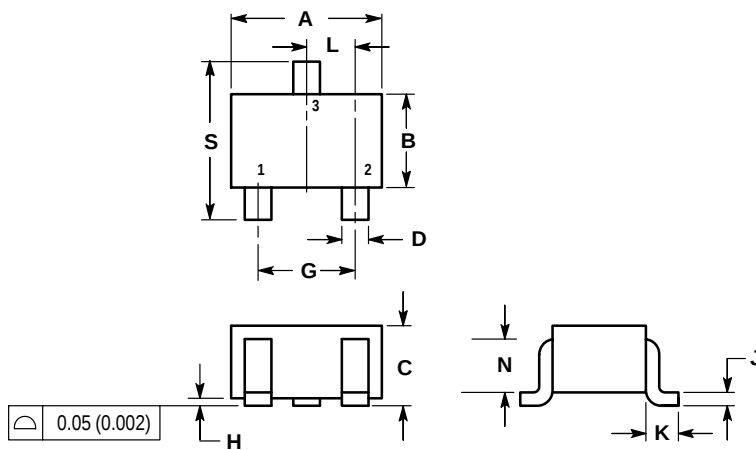

Figure 3. Forward Voltage

Figure 4. Leakage Current

Figure 5. Capacitance

LBAV70WT1G,S-LBAV70WT1G

SC-70

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.



DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.071	0.087	1.80	2.20
B	0.045	0.053	1.15	1.35
C	0.032	0.040	0.80	1.00
D	0.012	0.016	0.30	0.40
G	0.047	0.055	1.20	1.40
H	0.000	0.004	0.00	0.10
J	0.004	0.010	0.10	0.25
K	0.017 REF		0.425 REF	
L	0.026 BSC		0.650 BSC	
N	0.028 REF		0.700 REF	
S	0.079	0.095	2.00	2.40

